



DACO SEMICONDUCTOR CO., LTD.

MBRA60035CTL

LOW VF SCHOTTKY DIODE MODULE TYPE 600A

Features

High Surge Capability

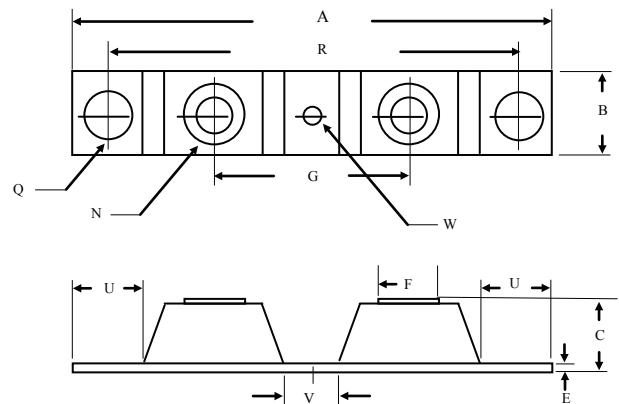
**600Amp Rectifier
35 Volts**

Maximum Ratings

Operating Temperature: -40 °C to +100 °C
Storage Temperature: -40 °C to +150 °C

Part Number	Maximum Recurrent Peak Reverse Voltage	Maximum RMS Voltage	Maximum DC Blocking Voltage
MBRA60035CTL	35V	25V	35V

HEAVY TWIN TOWER

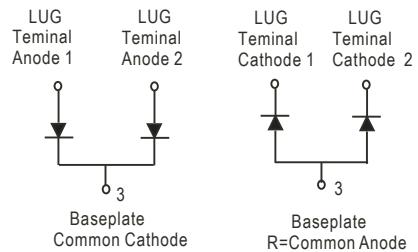


Electrical Characteristics @ 25 °C Unless Otherwise Specified

Average Forward Current (Per pkg)	I _{F(AV)}	600A	TC=100°C
Peak Forward Surge Current (Per leg)	I _{FSM}	4000A	8.3ms, half sine
Maximum Instantaneous Forward Voltage (Per leg)	V _F	0.60V	I _{FM} =300A; TJ=25 °C
Maximum Instantaneous Reverse Current At Rated DC Blocking Voltage (Per leg)	I _R	3.0mA	TJ = 25 °C
Maximum Thermal Resistance Junction To Case (Per leg)	R _{θ j c}	0.28 °C/W	TJ = 100 °C

NOTE :

- (1) Pulse Test: Pulse Width 300 μ sec. Duty Cycle < 2%



DIM	Inches		Millimeters	
	Min	Max	Min	Max
A	----	3.64	----	92.3
B	1.06	1.067	26.9	27.1
C	----	0.740	----	18.8
E	0.134	0.14	3.4	3.55
F	0.520	0.527	13.2	13.4
G	1.49	BSC	38.0	BSC
N	1/4-20 UNC FULL			
Q	0.275	0.290	6.99	7.37
R	3.150	BSC	80.01	BSC
U	0.512	----	13.0	----
V	0.449	0.472	11.4	12.0
W	0.180	0.195	4.57	4.95

